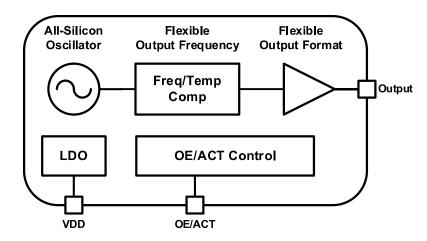
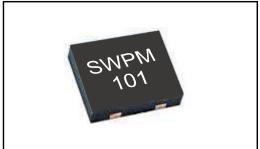
# SVARWAVE

## SWPM101 Arcadium™ Low Jitter CMOS Oscillator, 10 kHz to 212.5 MHz

The SWPM101 Arcadium™ all silicon CMOS oscillator utilizes proprietary frequency synthesis and sensor technologies to provide a quartz-free, MEMS-free, low jitter clock at any output frequency. The device is factory-programmed to a fixed frequency ranging from 10 kHz to 212.5 MHz with < 0.026 ppb resolution and maintains low jitter across its operating range. It uses on-chip temperature and strain sensors, and an advanced LC tank architecture to achieve excellent reliabilities even in high impact shock scenarios.

SWPM101's on-chip power supply filtering provides industry-leading power supply noise rejection, simplifying the task of generating low jitter clocks in noisy systems that use switched-mode power supplies. Offered in an industry-standard 3225 package, the SWPM101 has a dramatically simplified supply chain that enables StarWave to ship samples shortly after receipt of order. Specific frequency and OE/ACT are factory programmed at time of shipment, eliminating the long lead times associated with custom frequencies. This process also guarantees 100% electrical testing of every device before shipment.





#### **KEY FEATURES**

- Quartz-free and MEMS-free without mechanical moving parts
- · CMOS compatible output
- Available with frequencies from 10 kHz to 212.5 MHz
- Low jitter: 350 fs Typ RMS (12 kHz 20 MHz bandwidth)
- · Temperature stability:
  - ± 12 ppm (0 to 70°C)
  - ± 20 ppm (-20 to 85°C)
  - ± 35 ppm (-40 to 85°C)
  - ± 35 ppm (-40 to 105°C)
- Integrated LDO for on-chip power supply noise filtering
- Support continuous 1.8V to 3.3V V<sub>DD</sub> supply operation
- Industrial standard 3225 package footprints

## **APPLICATIONS**

- 1G/10G/40G/100G/200G Ethernet
- Servers, switches, storage, NICs, search acceleration
- · Test and measurement
- Clock and data recovery
- FPGA/ASIC clocking

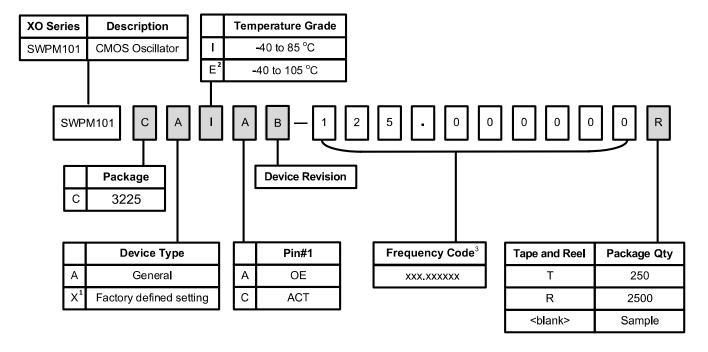
Pin Assignments				
OE/ACT	1	4	VDD	
GND	2	3	CLK	
Top view				
3225 package				

Pin#	Descriptions	
1	Selectable via ordering option	
	OE = Output Enable. Active High	
	ACT = Device Active. Active High	
2	GND = Ground	
3	CLK = Clock output	
4	VDD = Power supply	



## 1. Ordering Guide

The SWPM101 Oscillator supports options including frequency and OE/ACT pin, as shown in the chart below. Specific device configurations are programmed into the part at time of shipment, and samples are available in 2 weeks.



- 1. "X" refers to the ID for the unique configuration with factory-defined settings, the value ranges from "B" to "Z".
- 2. Contact starwavecorp.com/contact-us for advanced -40~105°C option.
- 3. For example: 125 MHz = 125.000000; 33.33333 MHz = 33.333330.



## 2. Electrical Specifications

**Table 2.1. Electrical Specifications** 

 $V_{DD}$  = 1.8 V, 2.5 or 3.3 V ± 5%,  $T_A$  = -40 to 105 °C

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Temperature Range	TA		<b>-40</b>	_	105	۰C
Frequency Range		CMOS	0.01	_	212.5	MHz
Supply Voltage	V <sub>DD</sub>		1.71		3.47	V
Supply Current	I <sub>DD</sub>	Tristate Hi-Z (OE = 0,output enable)	_	40	50	mA
(F <sub>CLK</sub> = 50 MHz)		Ready State (ACT = 0,standby)	_	1	2	mA
		CMOS (C <sub>L</sub> = 5 pF)	_	40	55	mA
Temperature Stability <sup>1</sup>	F <sub>STAB</sub>	0 to +70°C	-12	_	+12	ppm
		-20 to +85°C	-20	_	+20	ppm
		-40 to +85°C	-35	_	+35	ppm
		-40 to +105°C <sup>3</sup>	-35	_	+35	ppm
Frequency offset <sup>2</sup>	FOFFSET	0 to +70°C	-23	_	+18	ppm
		-20 to +85°C	-21	_	+18	ppm
		-40 to +85°C	-20	_	+20	ppm
		-40 to +105°C <sup>3</sup>	<b>-</b> 22	_	+20	ppm
Rise/Fall Time		CMOS (C <sub>L</sub> = 5 pF)	_	0.5	1.5	ns
(20% to 80% V <sub>PP</sub> )	DC.	CMOS (C = 5 75)	45			%
Duty Cycle	DC	CMOS ( $C_L = 5 pF$ )	45	_	55	
Output Enable (OE) <sup>4</sup>	VIH	_	0.7×V <sub>DD</sub>	_		V
	VIL	— — — — — — — — — — — — — — — — — — —	_	_	0.3×V <sub>DD</sub>	V
	T <sub>D</sub>	Output Disable Time, F <sub>CLK</sub> >10 MHz	_	<u> </u>	3	μs
0 / 15 11 //07/	TE	Output Enable Time, F <sub>CLK</sub> >10 MHz		_	20	μs
Output Enable (ACT) <sup>4</sup>	V <sub>IH</sub>	<del>-</del>	0.7×V <sub>DD</sub>	_	_	V
	VIL	_	_	_	0.3×V <sub>DD</sub>	V
	T <sub>D</sub>	Output Disable Time, F <sub>CLK</sub> >10 MHz	_	_	3	μs
	Ts	Device Standby time, F <sub>CLK</sub> >10 MHz	_	_	40	μs
	TE	Output Enable Time, F <sub>CLK</sub> >10 MHz	_	_	400	μs
Powerup Time	Tosc	Time from 0.9 × V <sub>DD</sub> until output frequency (F <sub>CLK</sub> ) within spec	_	_	4	ms
CMOS Output Option	V <sub>ОН</sub>	I <sub>OH</sub> = 8/6/4 mA for 3.3/2.5/1.8V V <sub>DD</sub>	0.83×V <sub>DD</sub>		_	V
Owios Output Option	Vol	I <sub>OL</sub> = 8/6/4 mA for 3.3/2.5/1.8V V <sub>DD</sub>			0.17×V <sub>DD</sub>	V
	V OL	10L - 0/0/4 HIA 101 3.3/2.3/1.0V VDD	_	_	U.1/^VDD	

- 1. Frequency / temperature characteristics with offset removed.
- 2. Inclusive of initial frequency tolerance at 25°C, 10-year aging at 25°C, and variations over supply voltage, load and humidity after soldering-reflow shift settles.
- 3. Contact starwavecorp.com/contact-us for advanced -40~105°C option.
- 4. OE/ACT includes a 50 k $\Omega$  pull-up to  $V_{\text{DD}}$  for OE/ACT active high.



Table 2.2. Clock Output Phase Jitter and PSRR

 $V_{DD}$  = 1.8 V, 2.5 or 3.3 V ± 5%,  $T_A$  = –40 to 105 °C

Parameter Syl		Test Condition/Comment	Min	Тур	Max	Unit
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1,2</sup>	фл	CMOS	_	350	_	fs
F <sub>CLK</sub> ≥ 10 MHz						
Spurs Induced by External Power Supply Noise,	PSRR	100 kHz sine wave		-76	_	dBc
50 mV <sub>pp</sub> Ripple.		200 kHz sine wave	_	-75		
CMOS 125 MHz Output		500 kHz sine wave	_	-75	_	
V <sub>DD</sub> = 1.8 V		1 MHz sine wave	_	-75	_	
Spurs Induced by External Power Supply Noise,	PSRR	100 kHz sine wave	_	-83	-	dBc
50 mV <sub>pp</sub> Ripple.		200 kHz sine wave	_	-83	_	
CMOS 125 MHz Output		500 kHz sine wave	_	-83	_	
V <sub>DD</sub> = 2.5 or 3.3 V		1 MHz sine wave	_	-82	_	

- 1. Applies to output frequency: 50, 100, 125 MHz.
- 2. Guaranteed by characterization. Jitter inclusive of any spurs.

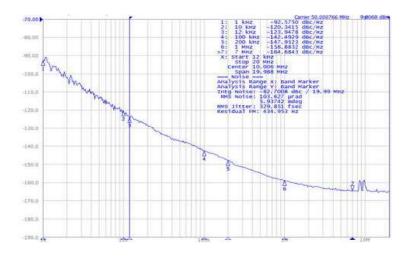


Figure 2.1. Phase Noise at 50 MHz

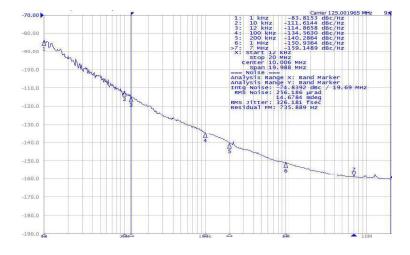


Figure 2.2. Phase Noise at 125 MHz



Table 2.3. Environmental Compliance and Package Information

Parameter	Test Condition
Moisture Sensitivity Level	2

#### Notes:

For additional product information not listed in the data sheet (e.g. RoHS Certifications, MSDS data, qualification data, REACH Declarations, ECCN codes, etc.), contact starwavecorp.com/contact-us

**Table 2.4. Thermal Conditions** 

Parameter	Symbol	Test Condition	Value	Unit
Thermal Resistance Junction to Ambient	ΘЈА	Still Air	108	°C/W
Thermal Resistance Junction to Board	ΘЈВ	Still Air	84	°C/W
Max Junction Temperature	TJ	Still Air	125	°C

## Table 2.5. Absolute Maximum Ratings<sup>1</sup>

Parameter	Symbol	Rating	Unit
Maximum Operating Temp	T <sub>AMAX</sub>	105	°C
Storage Temperature	Ts	-55 to 105	°C
Supply Voltage	V <sub>DD</sub>	-0.5 to 3.8	V
Input Voltage	Vin	-0.5 to VDD + 0.3	V
ESD HBM (JESD22-A114)	НВМ	4.0	kV
ESD CDM (JESD22-C101)	CDM	1.0	kV
Solder Temperature <sup>2</sup>	T <sub>PEAK</sub>	260	°C
Solder Time at T <sub>PEAK</sub> <sup>2</sup>	T <sub>P</sub>	20 - 40	sec

- 1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.
- 2. The device is compliant with JEDEC J-STD-020.



## 3. Package Outline

The figure below illustrates the package details for the SWPM101. The table below lists the values for the dimensions shown in the illustration.

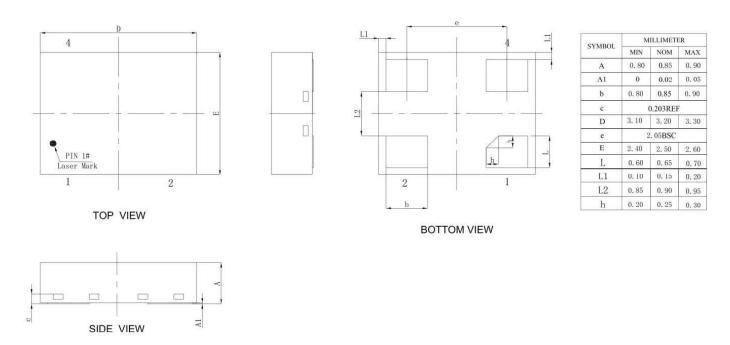


Figure 3.1. SWPM101 Outline Diagram

Table 3.1. Package Diagram Dimensions (mm)

Dimension	Min	Nom	Max
А	0.8	0.85	0.9
A1	0	0.02	0.05
b	0.80	0.85	0.90
С		0.203 REF	
D	3.10	3.20	3.30
e		2.05 BSC	
E	2.40	2.50	2.60
L	0.60	0.65	0.70
L1	0.10	0.15	0,20
L2	0.85	0.90	0.95
h	0.20	0.25	0.30

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.



#### 4. PCB Land Pattern

The figure below illustrates the PCB land pattern for the SWPM101. The table below lists the values for the dimensions shown in the illustration.

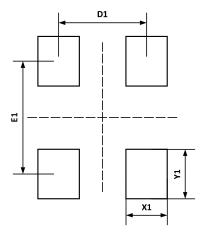


Figure 4.1. SWPM101 PCB Land Pattern

Table 4.1. PCB Land Pattern Dimensions (mm)

Dimension	Description	Value (mm)
X1	Width - leads on long sides	0.75
Y1	Height - leads on long sides	0.90
D1	Pitch in X directions of XLY1 leads	1.60
E1	Lead pitch XLY1 leads	2.05

## Notes:

The following notes and stencil design are shared as recommendations only. A customer or user may find it necessary to use different parameters and fine-tune their SMT process as required for their application and tooling.

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

## Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 0.8:1 for the pads.

#### **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



## 5. Top Marking

The figure below illustrates the mark specification for the SWPM101. The table below lists the line information.

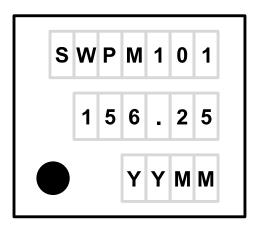


Figure 5.1. SWPM101 Top Mark

Table 5.1. SWPM101 Top Mark Description

Line	Position	Description
1	1-5	Device Name
2	1-5	Unique 5-digit Device Configuration Number
3	Position 1	Pin 1 orientation mark (dot)
	Position 2-3	Year (last two digits of the year), to be assigned by assembly site (ex: 2017 = 17)
	Position 4-5	Calendar Work Week number (1-53), to be assigned by assembly site



## 6. IMPORTANT NOTICE AND DISCLAIMER

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## 7. Revision History

Rev	Date	Description
1.01	Dec 2021	Adjusted the PCB land pattern dimensions
1.00	Sep 2021	With certain specification update
0.95	Jun 2021	Corrected the Ordering Guide Insert -40~105oC temperature range option Insert section "IMPORTANT NOTICE AND DISCLAIMER"
0.2	Mar 2021	Changed the frequency range and ordering guide
0.1	Feb 2021	Initial release